



SANYO Semiconductors

DATA SHEET

CPH3121 / CPH3221

— PNP / NPN Epitaxial Planar Silicon Transistors
DC / DC Converter Applications

Applications

- Relay drivers, lamp drivers, motor drivers, flash.

Features

- Adoption of MBIT processes.
- High current capacitance.
- Low collector-to-emitter saturation voltage.
- High-speed switching.
- Ultrasmall package facilitates miniaturization in end products (mounting height : 0.9mm).
- High allowable power dissipation.

Specifications (): CPH3121

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		(-)15	V
Collector-to-Emitter Voltage	V _{CEO}		(-12)15	V
Emitter-to-Base Voltage	V _{EBO}		(-)5	V
Collector Current	I _C		(-)3	A
Collector Current (Pulse)	I _{CP}		(-)5	A
Base Current	I _B		(-)600	mA
Collector Dissipation	P _C	Mounted on a ceramic board (600mm ² ×0.8mm)	0.9	W
Junction Temperature	T _j		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I _{CBO}	V _{CB} =(-)12V, I _E =0			(-)0.1	µA
Emitter Cutoff Current	I _{EBO}	V _{EB} =(-)4V, I _C =0			(-)0.1	µA
DC Current Gain	h _{FE}	V _{CE} =(-)2V, I _C =(-)500mA	200		560	
Gain-Bandwidth Product	f _T	V _{CE} =(-)2V, I _C =(-)500mA		(380)350		MHz
Output Capacitance	C _{ob}	V _{CB} =(-)10V, f=1MHz		(40)23		pF

Marking : CPH3121 : AS, CPH3221 : CS

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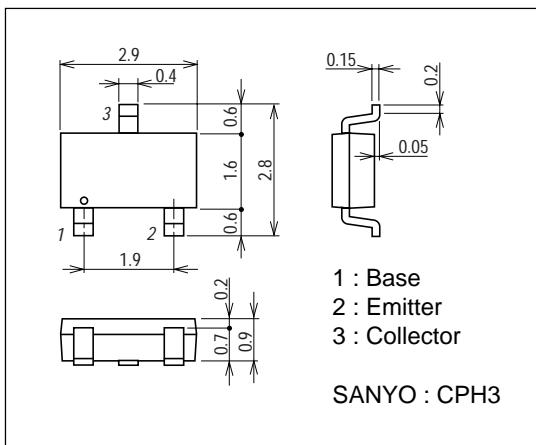
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = (-)1.5A, I_B = (-)30mA$		(-110)115	(-165)175	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = (-)1.5A, I_B = (-)30mA$		(-)0.85	(-)1.2	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = (-)10\mu A, I_E = 0$	(-)15			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = (-)1mA, R_{BE} = \infty$	(-12)15			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = (-)10\mu A, I_C = 0$	(-)5			V
Turn-ON Time	t_{on}	See specified Test Circuit.		(30)30		ns
Storage Time	t_{stg}	See specified Test Circuit.		(90)210		ns
Fall Time	t_f	See specified Test Circuit.		(14)11		ns

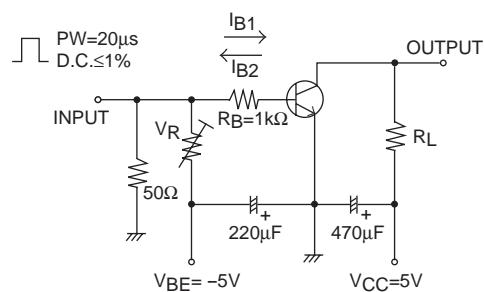
Package Dimensions

unit : mm

2150A

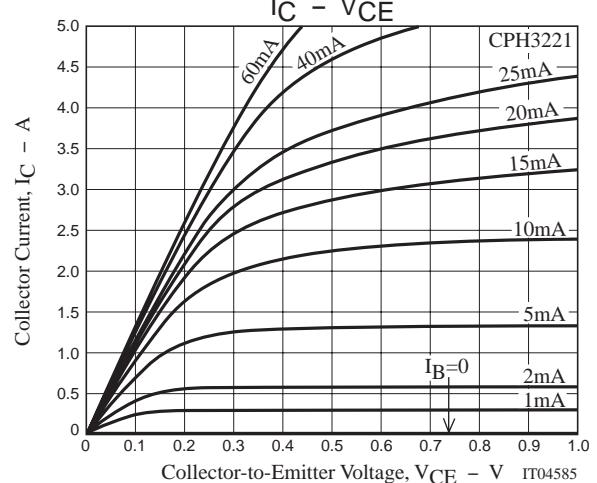
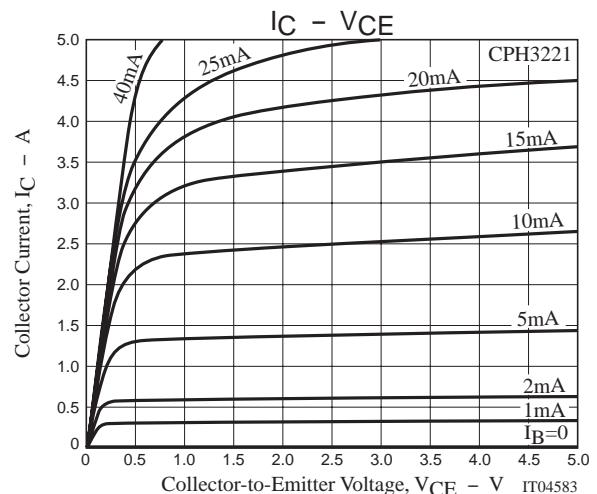
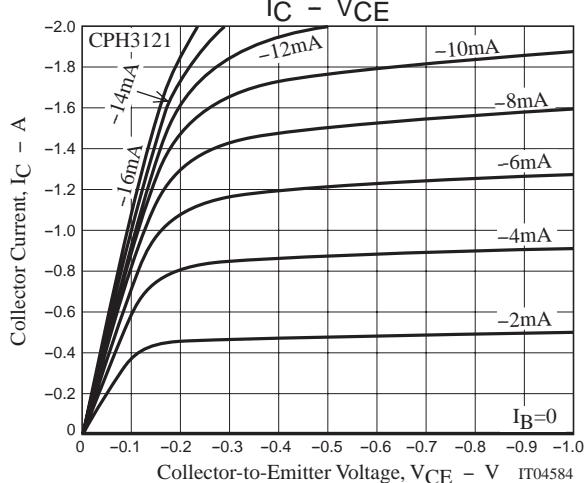
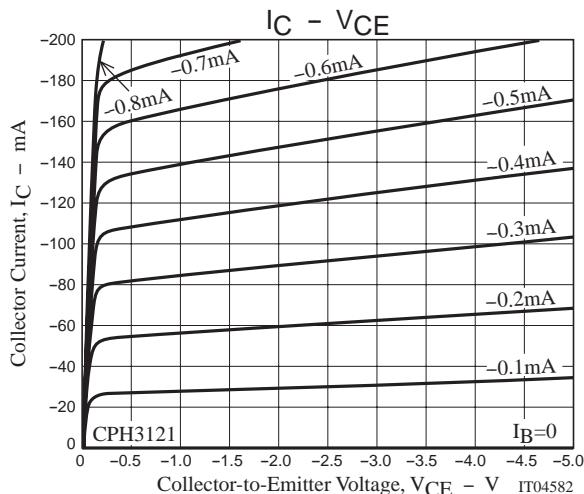


Switching Time Test Circuit

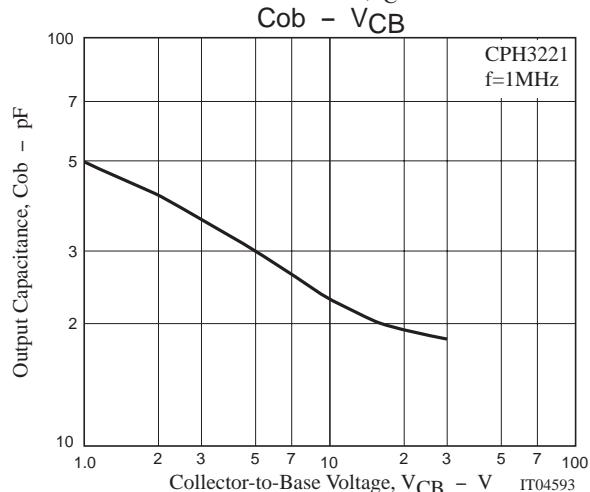
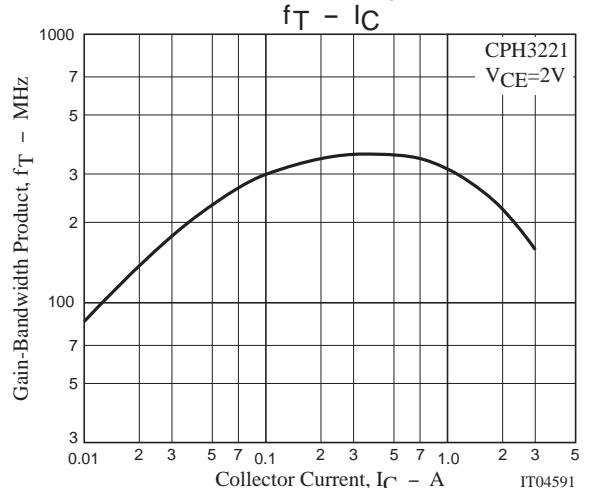
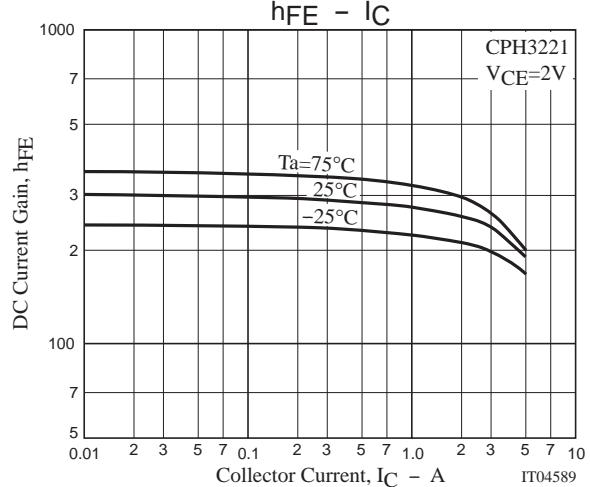
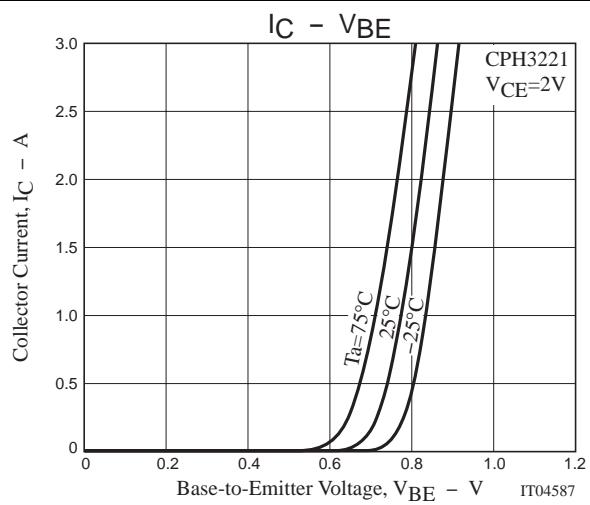
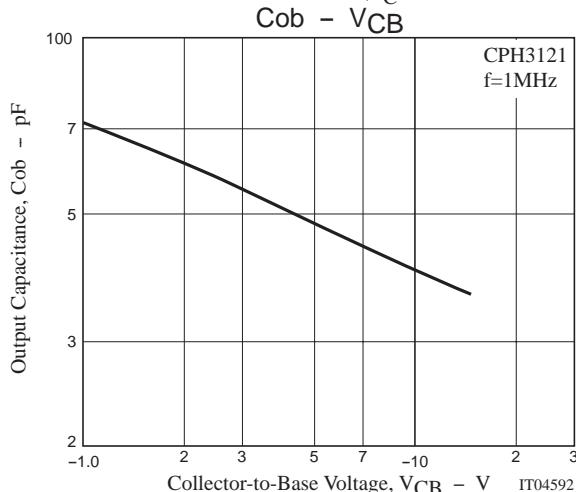
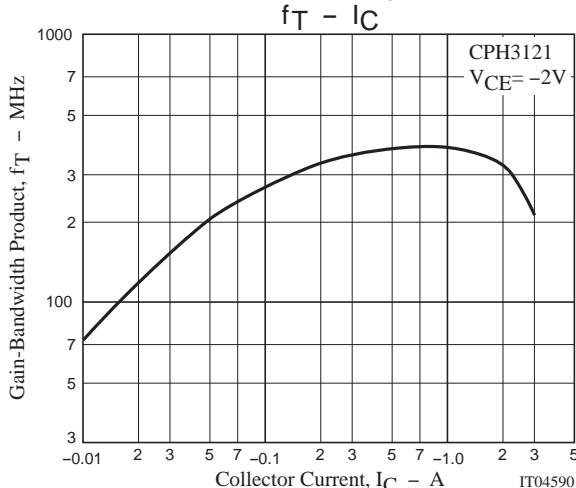
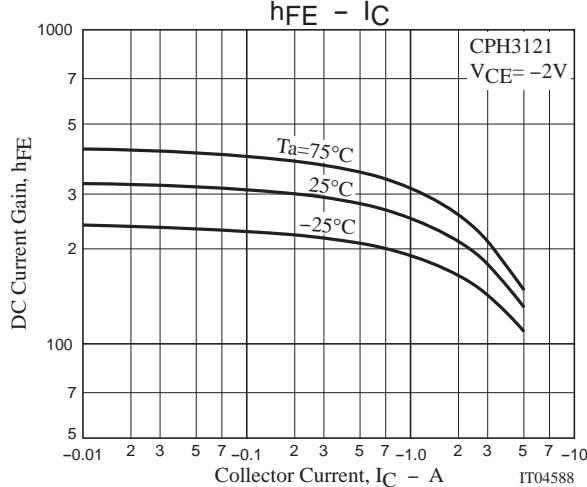
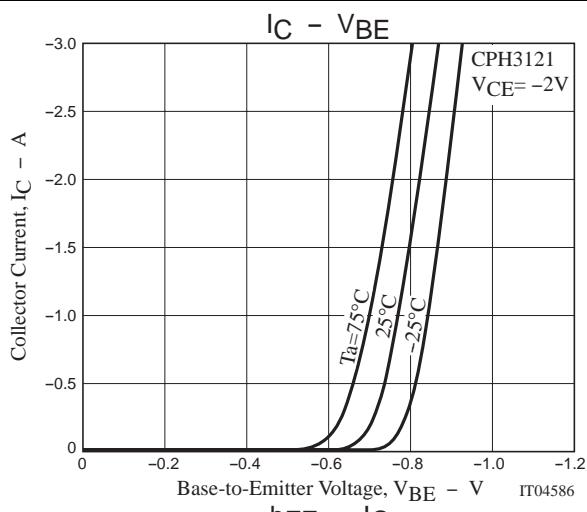


$$I_C = 20I_{B1} = -20I_{B2} = 1.5A$$

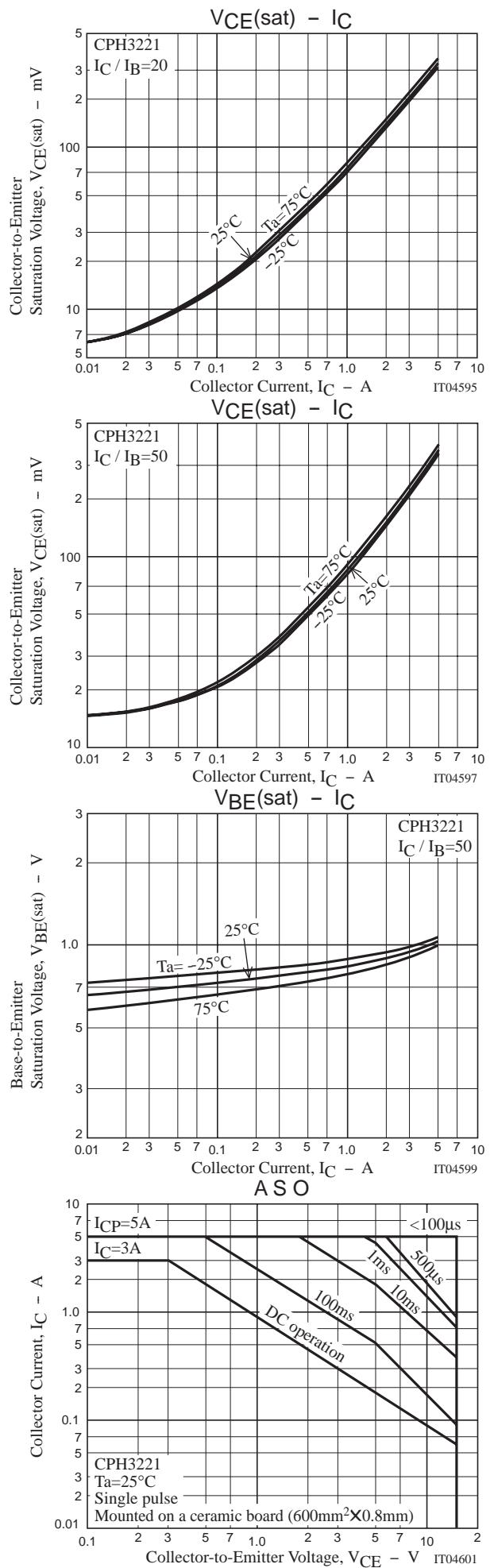
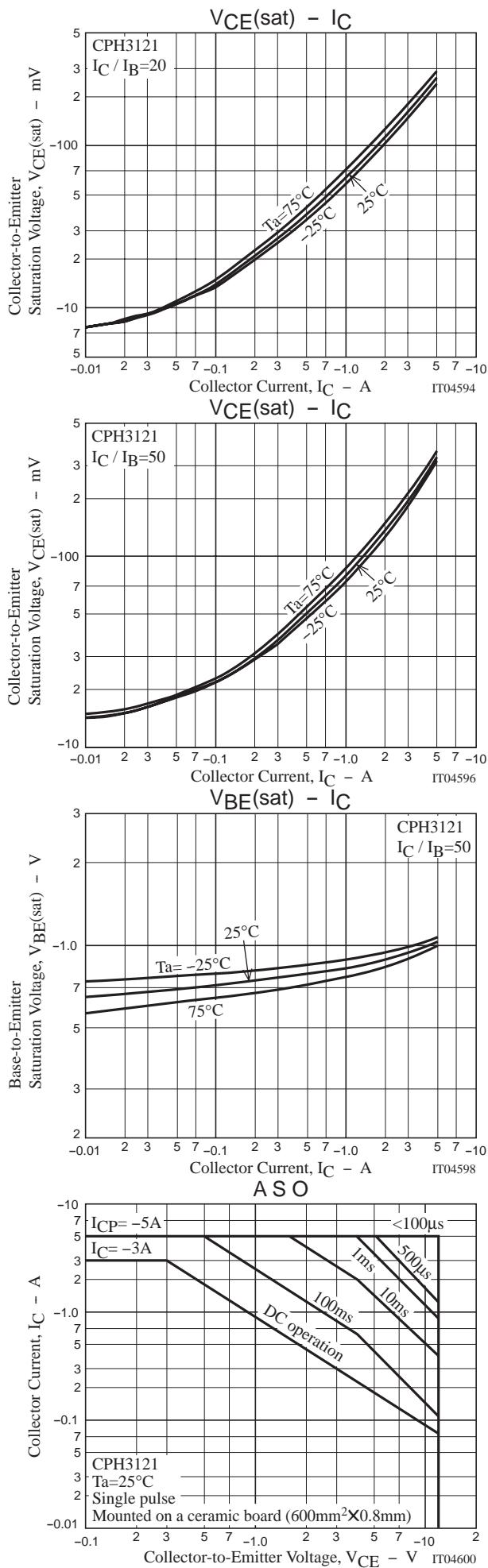
For PNP, the polarity is reversed.

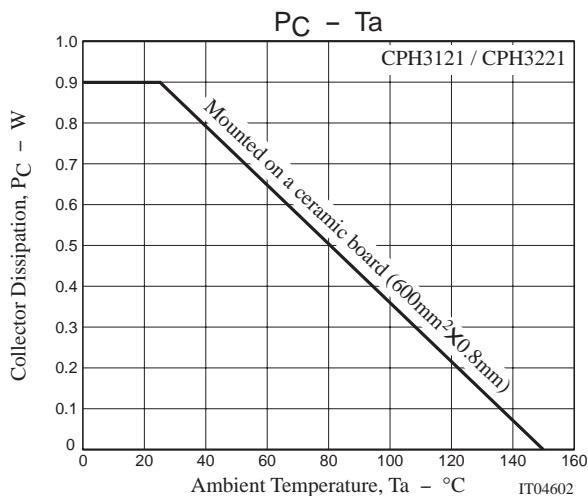


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